

FSA641 – 2:1 MIPI Switch, Featuring 2-Data and 1-Data Lane Configuration

Features

Switch Type	2:1
Signal Types	MIPI, DPHY
V _{CC}	2.65 to 4.3 V
Input Signals	0 to V _{CC}
Ron	7 Ω Typical HS MIPI 10 Ω Typical LS MIPI
ΔR _{ON}	0.75 Ω Typical HS & LS MIPI
I _{CC}	1 A Maximum
O _{IRR}	-50 dB Typical
X _{TALK}	-40 dB Typical
Bandwidth	1 GHz Typical
Channel-to-Channel Skew	15 ps Typical
Con	8 pF Typical
	20-Lead UMLP
Package	3.0x3.0x 0.55 mm, 0.4 mm Pitch
Ordering Information	FSA641UMX

Description

The FSA641 is a 2:1 MIPI switch made for 2-data lane and 1-data lane modules. This part is configured as a single-pole, double-throw switch (SPDT) and is optimized for switching between two high-speed or low-power MIPI sources. The FSA641 has specially been designed for the MIPI specification and allows connection to either a CSI or DSI module. The FSA641 features an extremely low on capacitance (C_{ON}) of 8 pF. The wide bandwidth (1 GHz) results in signals with minimum edge and phase distortion. Superior channel-to-channel crosstalk minimizes interference.

Related Resources

- For samples and questions, please contact: Analog.Switch@fairchildsemi.com.
- FSA641 Demonstration Board

Applications

- Cellular Phones, Smartphones
- Displays

Typical Application

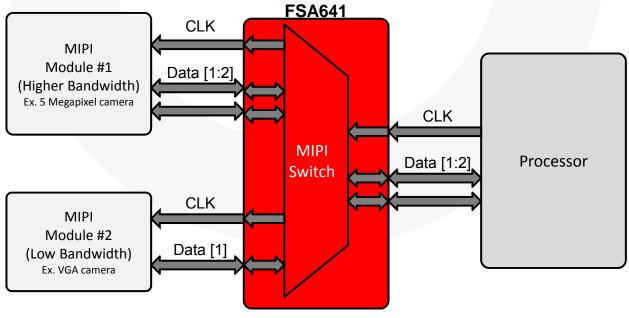
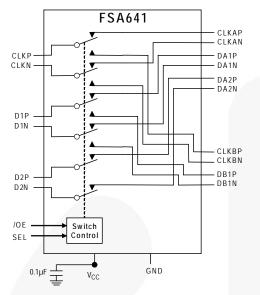


Figure 1. Mobile Phone Example

Pin Configuration



CLKP CLKBN CLKBP DB1N DB1P

20 19 18 17 16

CLKAP

D1P 2 14 CLKAN

D1N 3 1 13 DA1P

D2P 4 1 12 DA1N

D2N 5 1 7 8 9 10

/OE GND VCC SEL DA2N

Figure 2. Functional Block Diagram

Figure 3. Pin Assignments (Top Through View)

Pin Descriptions

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Pin #	Pin Name	Туре	Description
20	CLKP	I/O	Common positive clock path
1	CLKN	I/O	Common negative clock path
2	D1P	I/O	Common positive data 1 path
3	D1N	I/O	Common negative data 1 path
4	D2P	I/O	Common positive data 2 path
5	D2N	I/O	Common negative data 2 path
15	CLKAP	I/O	A-port positive clock path
14	CLKAN	I/O	A-port negative clock path
13	DA1P	I/O	A-port positive data 1 path
12	DA1N	I/O	A-port negative data 1 path
11	DA2P	I/O	A-port positive data 2 path
10	DA2N	I/O	A-port negative data 2 path
18	CLKBP	I/O	B-port positive clock path
19	CLKBN	I/O	B-port negative clock path
16	DB1P	I/O	B-port positive data 1 path
17	DB1N	I/O	B-port negative data 1 path
6	/OE	Input	Output Enable (Active Low)
7	GND	Ground	Ground
8	VCC	Supply	Power; 0.1 µF decoupling capacitor to ground recommended
9	SEL	Input	A-port or B-port Select pin 0=A-port, 1= B-port
Paddle	n/a	NC	Not Connected

Truth Table

SEL	/OE	Function
Don't Care	HIGH	Disconnect
LOW LOW		D1, D2, CLK=DA1, DA2, CLKA
HIGH	LOW	D1, CLK=DB1, CLKB; D2 OPEN

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Parameter			Unit
V _{CC}	Supply Voltage		-0.50	+5.25	V
V _{CNTRL}	DC Input Voltage (SEL, /OE) ⁽¹⁾		-0.5	V _{CC}	V
V _{SW}	DC Switch I/O Voltage ⁽¹⁾		-0.5	V _{CC} + 0.3	V
I _{IK}	DC Input Diode Current	-50		mA	
I _{OUT}	DC Output Current		50	mA	
T_{STG}	Storage Temperature		-65	+150	°C
		All Pins		6.5	
ESD	Human Body Model, JEDEC: JESD22-A114			8.0	kV
ESD		Power to GND	N. Committee	16.0	ΝV
	Charged Device Model, JEDEC: JESD22-C101	-		2.0	

Note:

1. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply Voltage	2.65	4.30	V
V _{CNTRL}	Control Input Voltage (SEL, /OE) ⁽²⁾	0	Vcc	V
V_{SW}	Switch I/O Voltage	-0.5	V_{CC}	V
T _A	Operating Temperature	-40	+85	°C

Note:

2. The control input must be held HIGH or LOW; it must not float.

DC Electrical Characteristics

All typical values are T_A=25°C unless otherwise specified.

Symbol	Parameter	Conditions	V _{cc} (V)	T _A =-40 to +85°C			Units
Symbol	or rarameter Conditions		VCC (V)	Min.	Тур.	Max.	Ullits
V _{IK}	Clamp Diode Voltage	I _{IN} =-18 mA	2.775			-1.2	V
I _{IN}	Control Input Leakage	V _{SW} =0 to 4.3 V	4.3	-1		1	μA
V	Innut Voltago High	V _{IN} =0 to V _{CC}	2.650 to 2.775	1.3			V
V _{IH}	Input Voltage High	VIN-U IO VCC	4.3	1.7			V
V _{IL}	Input Voltage Low	V_{IN} =0 to V_{CC}	2.650 to 2.775			0.5	V
loz	Off-State Leakage	A, B=0+0.3 V to V _{CC} -0.3	4.3	-2		2	μA
I _{CC}	Quiescent Supply Current	V _{CNTRL} =0 or V _{CC} , I _{OUT} =0	4.3			1.0	μA
I _{CCT}	Increase in I _{CC} Current Per Control Voltage and V _{CC}	V _{CNTRL} =1.8 V	2.775			1.5	μA

DC Electrical Characteristics, Low-Speed Mode

All typical values are T_A=25°C unless otherwise specified.

Symbol	Parameter	er Conditions V _{CC} (V)		T _A =-	40 to +	85°C	Units
Syllibol	r al allietei			Min.	Тур.	Max.	Units
R _{ON}	LS Switch On Resistance ⁽³⁾	V _{SW} =1.2 V, I _{ON} =-10 mA, Figu	ire 4 2.65		10	14	Ω
ΔR_{ON}	LS Delta R _{ON} ⁽⁴⁾	V _{SW} =1.2 V, I _{ON} =-10 mA (Intra	a-pair) 2.65		0.75		Ω

Notes:

- 3. Measured by the voltage drop between A/B and CLK/Dn pins at the indicated current through the switch.
- 4. Guaranteed by characterization.

DC Electrical Characteristics, High-Speed Mode

All typical values are T_A=25°C unless otherwise specified.

Symbol	Parameter	Conditions V _{cc} (V)		T _A =-	40 to +	85ºC	Units
Symbol	i arameter	Conditions	ACC (A)	Min.	Тур.	Max.	Oilles
R _{ON}	HS Switch On Resistance ⁽⁵⁾	V _{SW} =0.4 V, I _{ON} =-10 mA, Figure 4	2.65)	7.0	9.5	Ω
ΔR_{ON}	HS Delta R _{ON} ⁽⁶⁾	V _{SW} =0.4 V, I _{ON} =-10 mA (Intra-pair)	2.65		0.75		Ω

Notes:

- 5. Measured by the voltage drop between A, B, and Dn pins at the indicated current through the switch.
- 6. Guaranteed by characterization.

AC Electrical Characteristics

All values are at R_L=50 Ω and R_S=50 Ω and all typical values are V_{CC}=2.775 V at T_A=25°C unless otherwise specified.

Symbol	Parameter	Conditions V _{cc} (T _A =-4	T _A =-40°C to +85°C		
Symbol	Parameter	Conditions	V _{cc} (V)	Min.	Тур.	Max.	Units
O _{IRR}	Off Isolation ⁽⁷⁾	f=100 MHz, R_T =50 Ω Figure 14	2.775		-50		dB
Xtalk	Non-Adjacent Channel Crosstalk ⁽⁷⁾	f=100 MHz, R _T =50 Ω Figure 15	2.775		-40		dB
BW	-3db Bandwidth ⁽⁷⁾	C_L =0 pF, R_T =50 Ω Figure 13	2.775		1.0		GHz
t _{ON}	Turn-On Time SEL, /OE to Output	C _L =5 pF, V _{SW} =1.2 V Figure 6, Figure 7	2.650 to 2.775		20	37	ns
t _{OFF}	Turn-Off Time SEL, /OE to Output	C _L =5 pF, V _{SW} =1.2 V Figure 6, Figure 7	2.650 to 2.775		15	27	ns
t _{PD}	Propagation Delay ⁽⁷⁾	C _L =5 pF Figure 6, Figure 8	2.775		0.25		ns
t _{BBM}	Break-Before-Make Time	C _L =5 pF, V _{SW1} =V _{SW2} =1.2 V Figure 12	2.650 to 2.775	7	9	12	ns

Note:

AC Electrical Characteristics, High-Speed

All typical values are V_{CC}=2.775V at T_A=25°C unless otherwise specified.

Crossbal	Dovementer	Can dition a	T _A =-40°C to +85°C			l lmita
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
t _{SK(Part_Part)}	Channel-to-Channel Skew Across Multiple Parts ^(8,9)	TDR-Based Method (V _{SW} -0.2V _{PP} ,C _L = C _{ON})		40	80	ps
tsk(Chl_Chl)	Channel-to-Channel Skew Within a Single Part ⁽⁸⁾	TDR-Based Method (V _{SW} -0.2V _{PP} ,C _L = C _{ON})		15	30	ps
t _{SK(Pulse)}	Skew of Opposite Transitions in the Same Differential Channel ⁽⁸⁾	TDR-Based Method (V _{SW} -0.2V _{PP} ,C _L = C _{ON})		10	20	ps

Notes:

- 8. Guaranteed by characterization.
- 9. Assumes the same V_{CC} and temperature for all devices.

Capacitance

Cumbal	Donomotor	Conditions	T _A =-40°C to +85°C			Unito
Symbol	Symbol Parameter Conditions		Min.	Тур.	Max.	Units
C _{IN}	Control Pin Input Capacitance ⁽¹⁰⁾	V _{CC} =0 V		1.5		
C _{ON}	Dn/CLK- On Capacitance ⁽¹⁰⁾	V _{CC} =2.775 V, /OE=0V, f=1 MHz Figure 11		8.0		pF
C _{OFF}	Dn/CLK Off Capacitance ⁽⁹⁾	V _{CC} =2.775 V, /OE=2.775 V, f=1 MHz Figure 10		2.5		

Note:

^{7.} Guaranteed by characterization.

^{10.} Guaranteed by characterization.

Test Diagrams

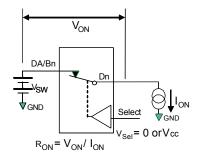
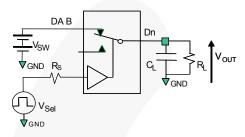


Figure 4. On Resistance



 R_L , R_S , an C_L ar fu ctions of th ap lication environment (se AC Tables for spe ific v lues) C_L inclu es test fixture an stra capacitance

Figure 6. AC Test Circuit Load

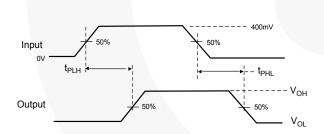


Figure 8. Propagation Delay (t_Rt_F - 500 ps)

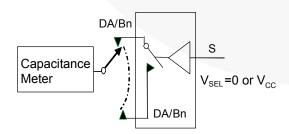
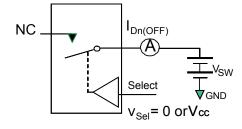


Figure 10. Channel Off Capacitance



**Each switch port is tested separately

Figure 5. Off Leakage

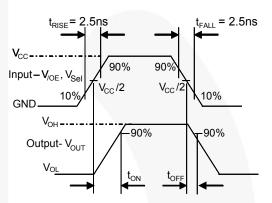


Figure 7. Turn-On / Turn-Off Waveforms

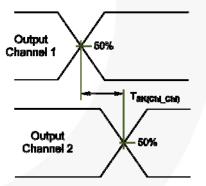


Figure 9. Channel-to-Channel Skew

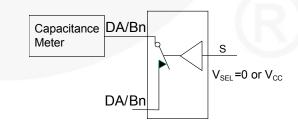


Figure 11. Channel On Capacitance

Test Diagrams (Continued)

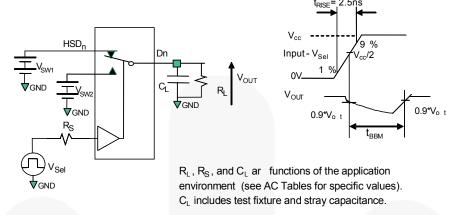


Figure 12. Break-Before-Make Interval Timing

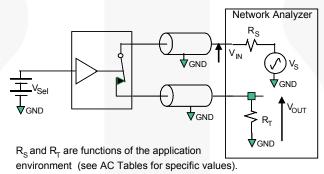
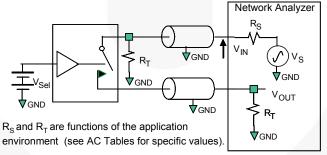
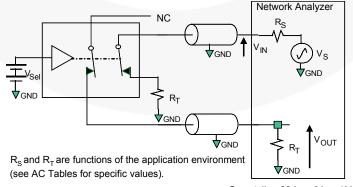


Figure 13. Bandwidth



Off isolation = 20 Log (V_{OUT} / V_{IN})

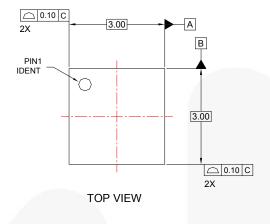
Figure 14. Channel Off Isolation

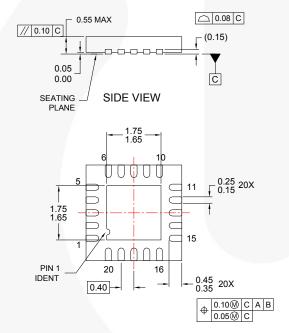


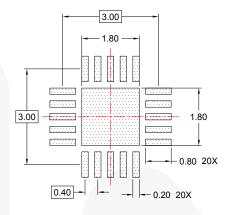
Crosstalk = 20 Log (V_{OUT} / V_{IN})

Figure 15. Non-Adjacent Channel-to-Channel Crosstalk

Physical Dimensions







RECOMMENDED LAND PATTERN

NOTES:

- A. PACKAGE CONFORMS TO JEDEC MO-248 VARIATION UEEE.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- D. LAND PATTERN RECOMMENDATION IS FROM PCB MATRIX CALCULATOR V2009.
- E. DRAWING FILENAME: MKT-UMLP20Brev1.

Figure 16. 20-Lead, Quad, Ultrathin Molded Leadless Package (UMLP), 3.0 x 3.0 mm

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BOTTOM VIEW

For current tape and reel specifications, visit Fairchild Semiconductor's online packaging area: http://www.fairchildsemi.com/packaging/3.0x3.0 UMLP Pack TNR Spec.pdf

Ordering Information

Part	Top	Operating Temperature	Package
Number	Mark	Range	
FSA641UMX	F641	-40 to +85°C	20-Lead, Quad, Ultrathin Molded Leadless Package (UMLP), 3.0 x 3.0 mm





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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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